

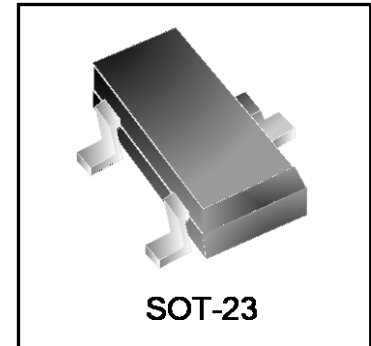
## NPN Silicon Transistor

### Features

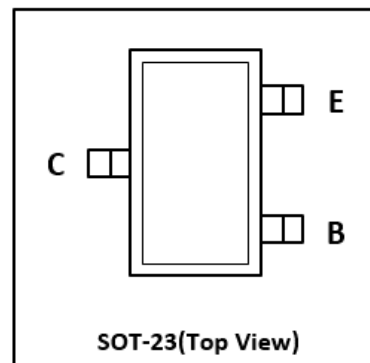
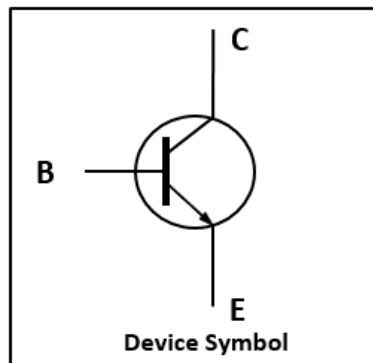
- Audio Frequency General Purpose Amplifier Applications
- Complementary to WT1162

### Mechanical Characteristics

- SOT-23 package
- Marking : Making Code
- RoHS Compliant



### Schematic & PIN Configuration



### Absolute Maximum Rating

Parameter	Symbol	Value	Unit
Collector Base Voltage	$V_{CBO}$	60	V
Collector Emitter Voltage	$V_{CEO}$	50	V
Emitter Base Voltage	$V_{EBO}$	5	V
Collector Current Continuous	$I_C$	150	mA
Collector Power Dissipation	$P_C$	150	mW
Junction Temperature	$T_J$	150	°C
Storage Temperature	$T_{stg}$	-50 ~ 150	°C

**Electrical Characteristics** ( $T_{amb}=25^{\circ}C$  unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 100\mu A, I_E = 0$	60	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 1mA, I_B = 0$	50	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 100\mu A, I_C = 0$	5	-	-	V
Collector Cut-off Current	$I_{CBO}$	$V_{CB} = 60V, I_E = 0$	-	-	100	nA
Emitter Cut-off Current	$I_{EBO}$	$V_{EB} = 5V, I_C = 0$	-	-	100	nA
DC Current Gain	$h_{FE}$	$V_{CE} = 6V, I_C = 2mA$	200	-	400	-
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 100mA, I_B = 10mA$	-	-	0.25	V
Transition Frequency	$f_T$	$V_{CE}=10V, I_C=1mA$	80	-	-	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB} = 10V, I_E = 0, f=1MHz$	-	2.0	-	pF
Noise Figure	<b>NF</b>	$V_{CE}=6V, I_C=0.1mA, f=1kHz, R_g=10k\Omega$	-	-	10	dB

**Typical Characteristics**

Figure 1. Static Characteristics

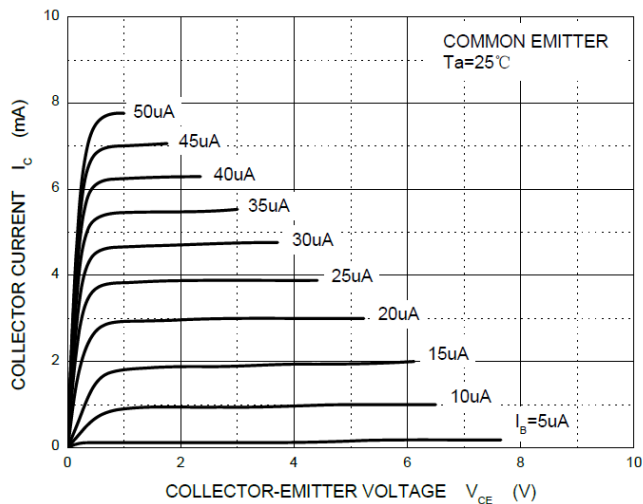


Figure 2.  $h_{FE}$  vs.  $I_C$

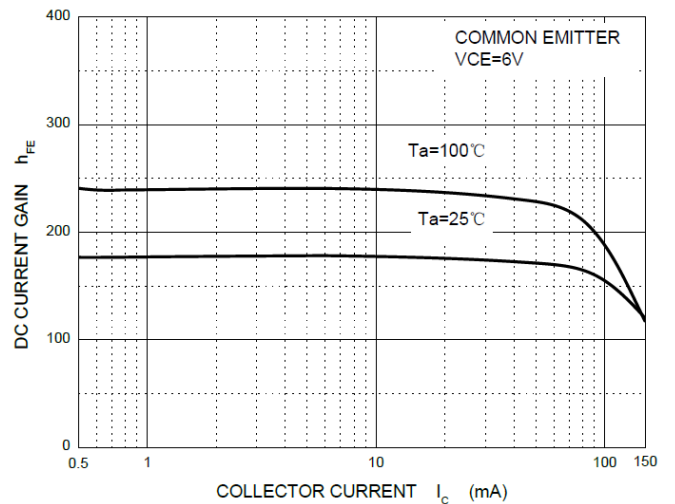


Figure 3.  $V_{CE(sat)}$  vs.  $I_C$

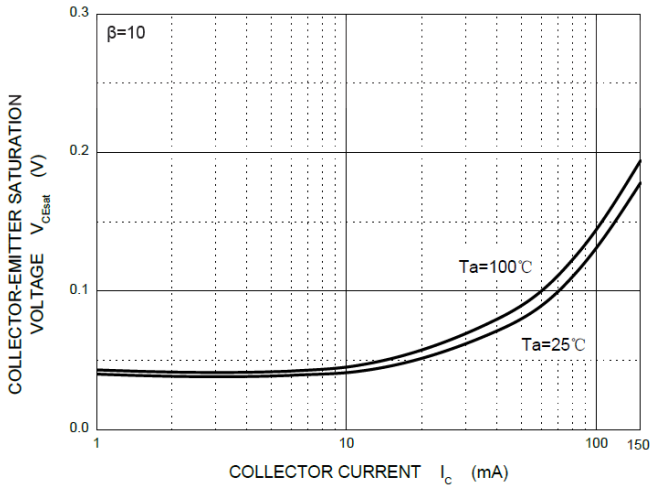


Figure 4.  $V_{BE(sat)}$  vs.  $I_C$

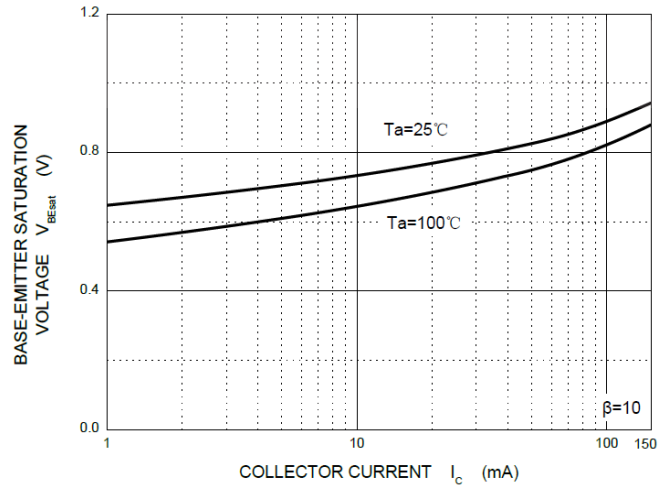


Figure 5.  $I_C$  vs.  $V_{BE}$

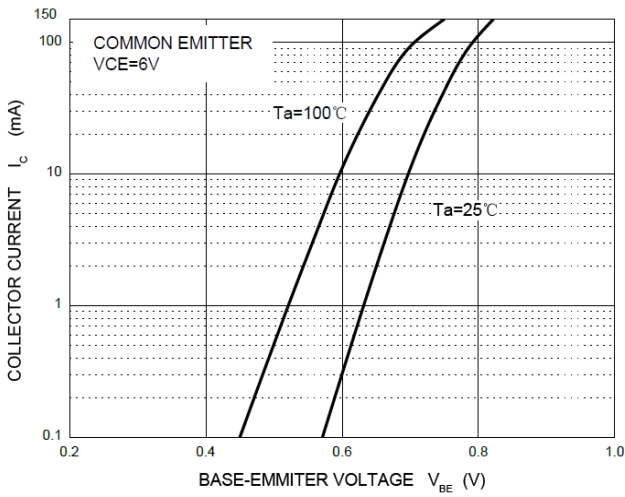


Figure 6.  $f_T$  vs.  $I_C$

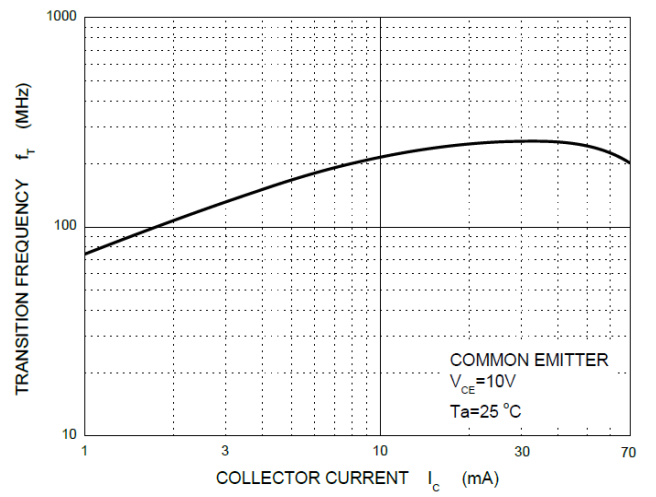


Figure 7.  $C_{ob} / C_{ib}$  vs.  $V_{CB} / V_{EB}$

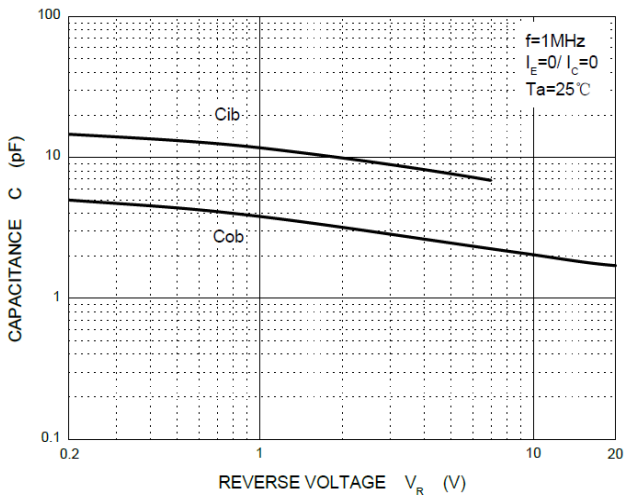
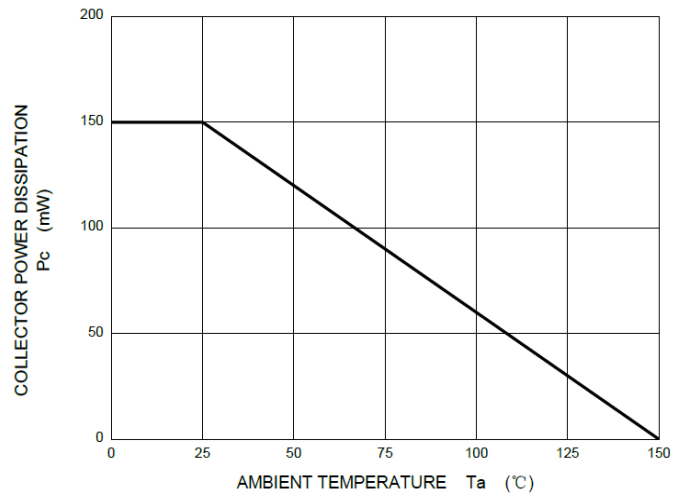


Figure 8.  $P_C$  vs.  $T_a$



Outline Drawing – SOT-23

**PACKAGE OUTLINE**

**SOT-23**

SYMBOL	MILLIMETER		INCHES	
	MIN	MAX	MIN	MAX
A	0.90	1.15	0.035	0.045
A1	0.00	0.10	0.000	0.004
b	0.30	0.50	0.012	0.020
c	0.08	0.15	0.003	0.006
D	2.80	3.00	0.110	0.118
E	2.25	2.55	0.089	0.100
E1	1.20	1.40	0.047	0.055
e	0.95 BSC		0.0374 BSC	
e1	1.80	2.00	0.071	0.079
L	0.45	0.65	0.018	0.026
θ	0	8°	0	8°

DIMENSIONS		
DIM	INCHES	MILLIMETERS
M	0.0795	2.02
C	0.0315	0.80
Z	0.111	2.82
e	0.037 BSC	0.95 BSC
e1	0.075 BSC	1.9 BSC
b	0.0315	0.80

**Notes**

1. Dimensioning and tolerances per ANSI Y14.5M, 1985.
2. Controlling Dimension: Inches
3. Pin 3 is the cathode (Unidirectional Only).
4. Dimensions are exclusive of mold flash and metal burrs.

Marking Codes

Rank	WT2712
Marking Code	

Package Information

Qty: 3k/Reel

CONTACT INFORMATION

No.1001, Shiwan (7) Road, Pudong District, Shanghai, P.R.China.201207

Tel: 86-21-68969993 Fax: 86-21-50757680 Email: [market@way-on.com](mailto:market@way-on.com)

WAYON website: <http://www.way-on.com>

For additional information, please contact your local Sales Representative.

**WAYON**® is registered trademark of Wayon Corporation.

*Specifications are subject to change without notice.  
The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time.  
Users should verify actual device performance in their specific applications.*

单击下面可查看定价，库存，交付和生命周期等信息

[>>WAY-ON\(维安\)](#)